NSN 5961-01-301-8255

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-301-8255 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.090 inches **End Application:** Alq-135b countermeasure **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 800.0 reverse voltage, peak and 1.8 forward voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average major **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector of standard range **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Diode fast recovery; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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